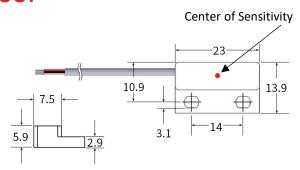
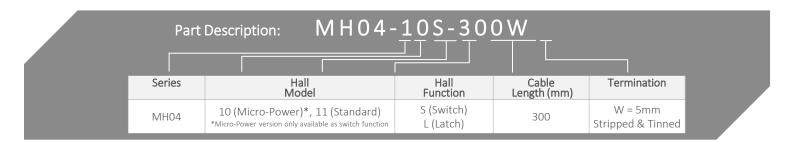


Series Datasheet standexelectronics.com

MH04 Series Micro-Power Hall Sensor

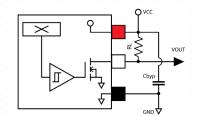
- Hall Effect Sensors offer solid state reliability, low power consumption, and consistent activation points over a wide temperature range in a rugged and environmentally isolated package.
- Micro-Power versions operate on 2.5-3.5V battery voltage with only 5μA average supply current vs. the industry average of 5mA
- Custom options include: output- switch, latch, etc., high temperature resistance, package design and much more.





Electrical & Environmental Characteristics		Micro-Power Switch			Standard Switch & Latch			11
Specification	Conditions	Min	Тур	Max	Min	Тур	Max	Unit
Supply Voltage	Operating	2.5	2.75	3.5	3	-	24	V
Output Leakage Current	V _{out} = Max Voltage	-	< 1	1	-	-		μΑ
Output On Voltage		-	100	300	-	185	500	mV
Awake Time		-	45	90	-	-	-	μs
Period		-	45	90	-	-	-	Ms
Duty Cycle		-	0.1	-	-	-	-	%
Chopping Frequency		-	340	-	-	800	-	kHz
Supply Current	Chip Awake	-	-	2	-	-	4	mA
	Chip Asleep	-	-	8	-	-	-	μΑ
	V _{cc} = 3.5V	-	6.7	10	-	-	-	μΑ
	V _{cc} = 12V	-	-	-	-	-	4	mA
Operating Temperature	*Higher temperature versions available	-40	-	+85*	-40	-40	+85*	С
Storage Temperature		-65	-	+105	-65	-65	+105	С

Magnetic Characteristics		Micro-Power Switch	Standard Switch	Standard Latch	Unit
Specification	Conditions	Тур	Тур	Тур	
Operation Point	V _{out} = Low (Output On)	37	35	22	G
Release Point	V _{out} = High (Output Off)	31	25	-23	G
Hysteresis		6	10	45	G



Notes:

- Add external pull-up resistor (RL) for sinking output between VCC and VOUT.
- Add external bypass capacitor (CBYP) close to the sensor to reduce external noise as needed.